

Title	Role of titanium and organic precursors in molecular layer deposition of “titanicone” hybrid materials
Authors	Muriqi, Arbresha;Nolan, Michael
Publication date	2022-11-02
Original Citation	Muriqi, A. and Nolan, M. (2022) ‘Role of titanium and organic precursors in molecular layer deposition of “titanicone” hybrid materials’, Beilstein Journal of Nanotechnology, 13, pp. 1240–1255. https://doi.org/10.3762/bjnano.13.103 .
Type of publication	Article (peer-reviewed);Article
Link to publisher's version	10.3762/bjnano.13.103
Rights	© 2022 Muriqi and Nolan; licensee Beilstein-Institut. This is an open access article licensed under the terms of the Beilstein-Institut Open Access License Agreement (https://www.beilstein-journals.org/bjnano/terms), which is identical to the Creative Commons Attribution 4.0 International License (https://creativecommons.org/licenses/by/4.0). The reuse of material under this license requires that the author(s), source and license are credited. Third-party material in this article could be subject to other licenses (typically indicated in the credit line), and in this case, users are required to obtain permission from the license holder to reuse the material. - https://creativecommons.org/licenses/by/4.0
Download date	2026-09-23 04:12:55
Item downloaded from	https://hdl.handle.net/10468/14557



University College Cork, Ireland
Coláiste na hOllscoile Corcaigh



Role of titanium and organic precursors in molecular layer deposition of “titanicone” hybrid materials

Arbresha Muriqi and Michael Nolan*

Full Research Paper

Open Access

Address:

Tyndall National Institute, University College Cork, Lee Maltings, T12 R5CP Cork, Ireland

Email:

Michael Nolan* - michael.nolan@tyndall.ie

* Corresponding author

Keywords:

density functional theory (DFT) studies; double reactions; surface chemistry; titanicone

Beilstein J. Nanotechnol. **2022**, *13*, 1240–1255.

<https://doi.org/10.3762/bjnano.13.103>

Received: 24 June 2022

Accepted: 20 October 2022

Published: 02 November 2022

Associate Editor: S. A. Claridge

© 2022 Muriqi and Nolan; licensee Beilstein-Institut.

License and terms: see end of document.

Abstract

The development of hybrid inorganic–organic films with well-controlled properties is important for many applications. Molecular layer deposition (MLD) allows the deposition of these hybrid films using sequential, self-limiting reactions, similar to atomic layer deposition (ALD). In this paper, we use first principles density functional theory (DFT) to investigate the growth mechanism of titanium-containing hybrid organic–inorganic MLD films, known as “titanicones”. We investigate in detail the chemistry between the most common Ti precursors, namely titanium tetrachloride (TiCl_4) and tetrakis(dimethylamido)titanium ($\text{Ti}(\text{DMA})_4$), and ethylene glycol (EG) and glycerol (GL) as the organic precursors. We analyse the impact of the substrate on the initial MLD reactions in titanicone film growth using three different surface models: anatase TiO_2 , rutile TiO_2 and Al_2O_3 . Calculated energetics show that while TiCl_4 is reactive towards the anatase and rutile TiO_2 surfaces, it is not reactive towards the Al_2O_3 surface. $\text{Ti}(\text{DMA})_4$ is reactive towards all surfaces. This is attributed to the stronger Ti–Cl bonds in TiCl_4 compared to Ti–N bonds in $\text{Ti}(\text{DMA})_4$. $\text{Ti}(\text{DMA})_4$ also shows high reactivity to the organics compared to TiCl_4 . Double reactions of EG and GL with the TiCl_3 species from TiCl_4 and TiDMA species from $\text{Ti}(\text{DMA})_4$ are also explored to better understand the origin of the different thicknesses of EG–titanicone and GL–titanicone films observed in experimental work. We find that EG and GL coupled with TiCl_4 can orient in a flat lying configuration on anatase while on rutile, the preferred orientation is upright. When combined with $\text{Ti}(\text{DMA})_4$, EG and GL prefer the flat lying configuration on all surfaces. This work shows that the choice of the surface and the metallic precursor has a major impact on the behaviour of organic species. DFT findings provide motivation to develop a low temperature rutile TiO_2 /titanicone film suggesting that the desired film growth could be achieved.

Introduction

Molecular layer deposition (MLD), a thin film deposition technique, has attracted significant attention in recent years as a suitable approach for the deposition of organic–inorganic

hybrid films for applications in several technological application areas, including packaging/encapsulation, electronics, batteries and biomedical applications [1–4]. MLD is very simi-

lar to the widely used atomic layer deposition (ALD) technique, which involves the fabrication of inorganic films used extensively in photovoltaics, (nano)electronics, energy storage and catalysis [5–8]. Similarly to ALD, MLD is based on sequential self-limiting reactions of readily vaporized inorganic precursors but the second reactant is a highly volatile organic species. Thus, in contrast to ALD, in MLD the deposition chemistry can be extended by including organic precursors, leading to the deposition of hybrid organic–inorganic MLD films [3,9]. Two organic precursors can also be employed to deposit pure organic MLD films, such as polymers [10–12]. Similar to ALD, MLD enables the deposition of conformal and smooth films with a controlled thickness at Angstrom level [3,9].

The advantages offered by hybrid organic–inorganic MLD films are that they are ultrathin films with high flexibility, have tunable properties and excellent mechanical and electronic properties resulting from the combination of the individual properties of the organic and inorganic components that are incorporated into the film [1,2,13–15].

A special class of hybrid organic–inorganic films are so-called metalcones, which are fabricated via MLD using organometallic precursors and organic alcohols. These films are described as $\text{O-M-O}-(\text{CH}_x)_y-\text{O-M-O}$. Metalcones are known to be flexible in nature due to the flexible organic backbones present in their architectures and with excellent mechanical properties at the atomic and molecular level arising from the organometallic precursors [16,17]. The first metalcone films were Al based and were known as “alucones” [18–20]. Soon after, other metalcone groups were developed, such as the Ti, Zn, Hf, Mg and V based metalcones known as “titanicones”, “zincones” [21,22], “hafnicones” [23], “magnesicones” [24] and “vanadicones” [25], respectively. While other organic backbones, e.g., aromatic rings, have been used, the field tends to use the term “metalcone” as a general description for these hybrid materials.

One of the most extensively researched metalcones are titanicones. Titanicones are deposited by coupling a titanium inorganic precursor, such as titanium tetrachloride (TiCl_4), with organic alcohols such as ethylene glycol (EG) [26–31], glycerol (GL) [29–31] or fumaric acid (FC) [32]. Tetrakis(dimethylamino)titanium ($\text{Ti}(\text{N}(\text{CH}_3)_2)_4$), henceforth denoted $\text{Ti}(\text{DMA})_4$ was also successfully employed as Ti source and combined with EG and GL to deposit titanicone films [33].

In ref [30] titanicone films were deposited using TiCl_4 as metal source and EG or GL as organic precursors. TiCl_4 –EG films and TiCl_4 –GL films were deposited on Si(100) wafers. XRR analysis found a growth per cycle (GPC) of ≈ 4.6 Å/cycle for TiCl_4 –EG films at 90 °C which decreases to 1.5 Å/cycle at

135 °C. It was assumed that this drop could be related to the desorption of unreacted TiCl_4 species at 135 °C. In addition, it was proposed that the reduction in growth rate could also be caused by the desorption of $\text{Ti}(\text{O}(\text{CH}_2)_2\text{O})_2$ species or double reactions of the organic precursor in which the molecule lies flat with both termini binding to Ti sites.

The thickness and thickness reduction with temperature increment observed for TiCl_4 –EG films was similar to the thickness and thickness reduction observed for alucone films grown using trimethylaluminium (TMA) and EG (4.0 Å/cycle at 85 °C to 0.4 Å/cycle at 175 °C) [18] and zincone films grown using diethylzinc (DEZ) and EG (4.0 Å/cycle at 90 °C to 0.25 Å/cycle at 170 °C) [21].

For TiCl_4 –GL films the growth rate was 2.8 Å/cycle at 130 °C and it decreased to 2.1 Å/cycle at 210 °C. The thickness of TiCl_4 –GL films was similar to the thickness of alucone films grown using TMA and GL (2.5 Å/cycle) [34]. Similar growth rates of TiCl_4 –EG and TiCl_4 –GL films were achieved also in ref. [31] (TiCl_4 –EG: 4.5 Å/cycle at 115 °C; TiCl_4 –GL: 2.2 Å/cycle at 150 °C).

Compared to EG, GL has an extra OH group that increases the bridging between the polymer chains in the film and this also improves the stability of the film. Nanoindentation experiments [30] showed also that GL-based titanicones have much higher elastic modulus and higher hardness compared to EG-based titanicones. Annealing experiments indicated a higher thermal stability for GL-based titanicones as well [30].

$\text{Ti}(\text{DMA})_4$ is another Ti-based inorganic precursor that was investigated as an alternative to TiCl_4 as the titanium precursor. $\text{Ti}(\text{DMA})_4$ was combined with EG and GL to deposit titanicone films in a temperature range from 80 °C to 160 °C on an Si substrate with 100 nm thermal oxide. In situ ellipsometry revealed for EG-based titanicones that the growth initiates but terminates after only 5 to 10 cycles, while for GL-based titanicones the growth proceeds and films have a GPC of 0.9 Å/cycle to 0.2 Å/cycle as the temperature increases. This is due to the double reaction phenomenon, which for EG removes both the reactive OH groups required to couple with the Ti precursor, while even with a double reaction, GL has a third OH group available to couple to the $\text{Ti}(\text{DMA})_4$ precursor in the next cycle [33]. $\text{Ti}(\text{DMA})_4$ inorganic precursor is well known and widely used in ALD for the deposition of TiO_2 and TiN films by thermal and plasma-enhanced processes [35,36].

As described above, TiCl_4 and $\text{Ti}(\text{DMA})_4$ were successfully employed in MLD of titanicone films [30,33]. While TiCl_4 is a small halide molecule that has Ti–Cl bonds, $\text{Ti}(\text{DMA})_4$ is a

bulkier molecule with Ti–N bonds. Bond dissociation energy values for the breakage of the Ti–Cl and Ti–N bonds serve as a measure of the stability of these precursors and these are 494 kJ/mol and 464 kJ/mol for Ti–Cl and Ti–N, respectively. Bond dissociation energies indicate that a lower energy is needed to break the Ti–N bond compared to the Ti–Cl bond and hence a higher reactivity for the $\text{Ti}(\text{DMA})_4$ precursor towards the surface and towards the co-reactant is expected.

In addition, due to the bulky DMA ligands of $\text{Ti}(\text{DMA})_4$, the “reservoir” effect, which is very common for small molecules such as TiCl_4 [30], DEZ [21] and TMA [37] and which leads to uncontrolled growth is avoided. Moreover, the ligand elimination reactions of the $\text{Ti}(\text{DMA})_4$ process yield $\text{H}-\text{N}(\text{CH}_3)_2$ by-products. In contrast this is non-corrosive compared to HCl by-products released during the TiCl_4 process. For TiCl_4 this is considered a significant drawback [38].

Fumaric acid (FC) is another alcohol organic precursor that was used to deposit titaniconic films using TiCl_4 on an Si substrate in a temperature range of 180 °C to 350 °C. A temperature-dependent growth characteristic was observed with the growth rate decreasing from 1.10 Å/cycle at 180 °C to 0.49 Å/cycle at 300 °C. This reduction was attributed to the increased thermal motion and desorption of molecules on the growth surface. FTIR spectra indicated that the hybrid film shows a stable bridging bonding mode between Ti and the acid group at temperatures under 200 °C and a high bridging/bidentate mixed bonding mode at temperatures over 250 °C and 300 °C [32].

Many studies show that the desired properties and the target thickness of a metalconic MLD film are not actually achieved. To help understand this, first principles density functional theory (DFT) calculations have been employed to explore the reaction mechanisms, energetics and the role of the organic precursors on the growth of hybrid films [24,39–41]. DFT studies show that the aliphatic diol precursors, namely EG and GL, when combined with TMA, undergo double reactions, binding with the surface fragments through the two terminal OH groups, and this phenomenon reduces the number of active sites and terminates the surface growth [39].

However, DFT results also show that this scheme depends on the metal precursor and the surface as the same aliphatic precursors behave differently when combined with $\text{Mg}(\text{Cp})_2$; EG still prefers to orient in a flat configuration and react twice with the surface, while GL prefers to lie in an upright configuration. This yields thicker GL-based magnesiconic films, consistent with the experimental observations [24].

DFT studies and experimental work show that aromatic organics can be a better option for the growth of thicker, more flexible and more stable hybrid films. This because aromatic molecules, due to their stiff backbone prefer to orient in a vertical configuration and avoid the double reactions [40,42]. Such hybrid films are known as “metal–organic” films. These also offer the advantage of allowing the facile tuning of the properties of the organic component through ring functionalisation, without impacting on the stability of the resulting films.

Many Ti–organic MLD processes have been developed by using different aromatic molecules as organic precursors. In ref [43], TiCl_4 was coupled with 4-aminophenol (AP) to deposit $\text{Ti}-(\text{O}-\text{C}_6\text{H}_4-\text{N}=\text{N})$ thin films with an essentially ideal growth rate of 10–11 Å/cycle at a temperature range of 120–160 °C. The deposited films were of high quality and stable in air. The high growth rates are attributed to the rigid structure of AP and the fact that Cl ligands of TiCl_4 are small and do not cause steric hindrance.

In another study, Ti–organic films were deposited using TiCl_4 and the homo/heterobifunctional aromatic molecules hydroquinone (HQ), 4-aminophenol (AP), *p*-phenylenediamine (PDA) and 4,4'-oxydianiline (ODA). All films were deposited on a Si surface. All four processes yielded amorphous Ti–organic films. A growth rate of 10–11 Å/cycle was achieved for the TiCl_4 –AP process, which is higher when compared to the growth rates 4.3 Å/cycle, 1.2 Å/cycle and 1.4 Å/cycle for TiCl_4 –HQ, TiCl_4 –PDA and TiCl_4 –ODA processes, respectively. The results are attributed the higher reactivity of the OH group with TiCl_4 in comparison to the NH_2 group and the higher tendency of the heterobifunctional organic precursor to orientate in an upright configuration and avoid unwanted double reactions on the surface [42].

TiCl_4 was also coupled with 4,4'-oxydianiline (ODA) to deposit the $(-\text{Ti}-\text{N}-\text{C}_6\text{H}_4-\text{O}-\text{C}_6\text{H}_4-\text{N}-)_n$ thin films. Films were deposited on an Si surface in two temperature ranges, 160–230 °C and 250–490 °C. The growth rate increases with increasing temperature, from 0.3 Å/cycle at 160 °C to 1.1 Å/cycle at 490 °C. Films deposited at a higher temperature were also more stable in atmosphere compared to films deposited at low temperatures [44].

Because of the similarity with TiO_2 ALD films, titaniconic films are promising for electronics and solar applications [45] and may be used for biological implants as well. As TiO_2 films have catalytic and photocatalytic properties [46] porous TiO_2 frameworks formed by the annealing of titaniconic films may serve as catalytic supports [47]. Titaniconic films can also be pyrolyzed under Ar to yield conducting TiO_2 /carbon composite films with

important electrochemical applications as electrodes for Li ion batteries or pseudocapacitance supercapacitors [31]. These films were also employed as coatings of nano Si electrodes and successfully improved their performance [48].

As described above, different titanocene and Ti–organic MLD processes have been developed and although first principles density functional theory (DFT) simulations have recently been used to explore the reaction mechanism in Ti–organic MLD film growth [42], such a study that explores the surface reactions and the precursor chemistry in titanocene MLD film growth and the role of the precursor chemistries is still lacking.

In this study we investigate the molecular mechanism of formation of titanocene films on anatase TiO_2 , rutile TiO_2 and Al_2O_3 surfaces using TiCl_4 or $\text{Ti}(\text{DMA})_4$ as Ti source and EG or GL as organic components. Calculated energetics suggest a higher reactivity of $\text{Ti}(\text{DMA})_4$ towards the selected surfaces and the organic molecules compared to TiCl_4 . This is due to the stronger Ti–Cl bonds in TiCl_4 compared to Ti–N bonds in $\text{Ti}(\text{DMA})_4$. We also found that the choice of surface and inorganic precursors can influence the behavior of organic molecules by allowing or preventing undesirable double reactions. Based on the calculated energetics we propose that a low temperature rutile $\text{TiO}_2/\text{TiCl}_4$ –EG process and rutile $\text{TiO}_2/\text{TiCl}_4$ –GL process can lead to thicker hybrid films.

Computational Methods

All DFT calculations in this work were performed using the Vienna Ab initio Simulation Package (VASP) version 5.4 [49]. Titanocene films were modelled on an anatase TiO_2 (101) surface with a coverage of 1 ML OH, rutile TiO_2 (110) surface with a coverage of 0.75 ML OH, and an Al_2O_3 (0001) surface at a coverage 0.50 ML OH [50,51]. These surface models interact with titanium tetrachloride (TiCl_4) and tetrakis(dimethylamido)titanium ($\text{Ti}(\text{DMA})_4$) inorganic precursors and then ethylene glycol (EG) and glycerol (GL) organic co-reactants.

The valence electron–core electron interactions are described by projector augmented wave potentials (PAW) [52] and the valence electron configurations are: Ti: $3d^3 4s^1$, Al: $3s^2 3p^1$, O: $2s^2 2p^4$, Cl: $3s^2 3p^5$, C: $2s^2 2p^2$ and H: $1s^1$. Calculations were performed using the Perdew–Burke–Ernzerhof (PBE) exchange–correlation functional [53]. The employed convergence criterion for the energy was 1×10^{-4} eV while that for the forces was -2×10^{-2} eV/Å. The geometry was optimized by relaxing the ionic positions using an energy cut-off of 400 eV as well as a Monkhorst–Pack $\mathbf{k}$ -point sampling grid of $(3 \times 3 \times 1)$. The lattice parameters are $a = 20.612$, $b = 15.164$, $c = 24.399$ and $\alpha = \beta = \gamma = 90^\circ$ for the anatase TiO_2 surface model,

$a = 11.846$, $b = 13.051$, $c = 33.870$ and $\alpha = \beta = \gamma = 90^\circ$ for the rutile TiO_2 surface model and $a = b = 19.228$, $c = 40.627$ and $\alpha = \beta = 90^\circ$, $\gamma = 120^\circ$ for the Al_2O_3 surface model. The surfaces are 2, 4 and 5 layers thick for anatase (101), rutile (110) and Al_2O_3 (0001).

Reaction energetics were calculated using:

$$E = \sum E_p - \sum E_r$$

Here E_p is the energy of products and E_r is the energy of reactants.

For the example of TiCl_4 adsorbing on the hydroxylated surfaces the energy was calculated as follows:

$$E_{\text{ads}} = E_{\text{TiCl}_4\text{--HO--surface}} - (E_{\text{TiCl}_4} + E_{\text{HO--surface}}), \quad (1)$$

where $E_{\text{TiCl}_4\text{--HO--surface}}$ is the total energy of TiCl_4 adsorbed on hydroxylated surface, E_{TiCl_4} is the total energy of free TiCl_4 molecule and $E_{\text{HO--surface}}$ is the total energy of the hydroxylated surface. Energetics of ligand elimination can be calculated from:

$$E_{\text{ads}} = (E_{\text{TiCl}_3\text{--O--surface}} + E_{\text{HCl}}) - (E_{\text{TiCl}_4\text{--HO--surface}}), \quad (2)$$

where a HCl molecule is eliminated. A similar equation is used for elimination of another HCl to give TiCl_2 on the TiO_2 surface.

For the example of EG interacting on a TiCl_3 -terminated surface the energy was calculated as follows:

$$E_{\text{int}} = (E_{\text{EG--TiCl}_2\text{--O--surface}} + E_{\text{HCl}}) - (E_{\text{EG}} + E_{\text{TiCl}_3\text{--O--surface}}), \quad (3)$$

where $E_{\text{EG--TiCl}_2\text{--O--surface}}$ is the total energy of EG bound to TiCl_4 on the hydroxylated surface, E_{HCl} is the total energy of a free HCl molecule released as by-product, E_{EG} is the total energy of the EG molecule and $E_{\text{TiCl}_3\text{--O--surface}}$ is the total energy of TiCl_3 -terminated hydroxylated surface. In computing the energies in Equation 1 and Equation 2, we also employ van der Waals interactions using the DFT–D3 parameterisation [54]. Similar energy expressions are used for the $\text{Ti}(\text{DMA})_4$ precursor.

The underlying data files are available at <https://github.com/ArbreshaMuriqi/Titanicene>.

Results and Discussion

Surface models of $\text{TiCl}_3/\text{TiCl}_2$ -terminated anatase/rutile TiO_2 and Al_2O_3 after the TiCl_4 pulse

As oxide/metal-oxide films are of high interest, we explored the feasibility of anatase TiO_2 /titanicene, rutile TiO_2 /titanicene and Al_2O_3 /titanicene film formation. This is a common approach in modelling MLD chemistry [24,39–41]. We performed fundamental investigation on the interactions between the hydroxylated anatase TiO_2 , hydroxylated rutile TiO_2 and hydroxylated Al_2O_3 surfaces with TiCl_4 and EG or GL precursors. The hydroxylated surfaces that results from the interactions with water and before the introduction of TiCl_4 are taken from previous studies [50,51].

In the first calculations we have calculated the interaction energies of the TiCl_4 molecule on the selected surfaces. These energies are -0.29 eV for the anatase TiO_2 , -0.22 eV for the rutile TiO_2 and 0.87 eV for the Al_2O_3 . These energies indicate that TiCl_4 will adsorb favourably, although with a small energy gain, on the anatase TiO_2 surface and rutile TiO_2 surface and will not adsorb on the Al_2O_3 surface. A previous study reports that TiO_2 films grow well using TiCl_4 and H_2O on amorphous Al_2O_3 [55]. However, in our case, the Al_2O_3 surface model we use is crystalline. It is well known that in an amorphous surface the molecular mobility is significantly higher than in any corre-

sponding crystalline form and there is a lower coordination number for atoms in the surface which gives rise to enhanced chemical reactivity of the amorphous surface. These results show that the choice of the surface can have a major impact on the initial deposition steps.

As we found that the adsorption of TiCl_4 was not favourable on the Al_2O_3 surface, we continued with only the anatase TiO_2 surface models and the rutile TiO_2 surface models.

Next, we investigated the first and second ligand loss reactions of TiCl_4 , which involve the proton transfer from the surface OH groups to the Cl ligands of TiCl_4 to form HCl as by-product, and the formation of new Ti–O bonds between the TiCl_4 molecule and surface oxygen. During the first ligand loss reaction, TiCl_4 forms one new Ti–O bond with the surface and one HCl molecule is released. This reaction leaves the surface covered with three Cl ligands, $\text{TiO}_2\text{--TiCl}_3$. During the second ligand loss reaction TiCl_4 forms a second new Ti–O bond with the surface and a second HCl molecule is released. After this reaction the surface is left covered with two Cl ligands, $\text{TiO}_2\text{--TiCl}_2$. The coordination number of Ti in the TiCl_4 molecule is four and remains unchanged during the first and second ligand loss reactions. Atomic structures of the anatase TiO_2 surface and rutile TiO_2 surface after adsorption of one TiCl_4 molecule and the elimination of the first and second ligand of TiCl_4 are presented in Figure 1. Calculated interaction and ligand loss energies of

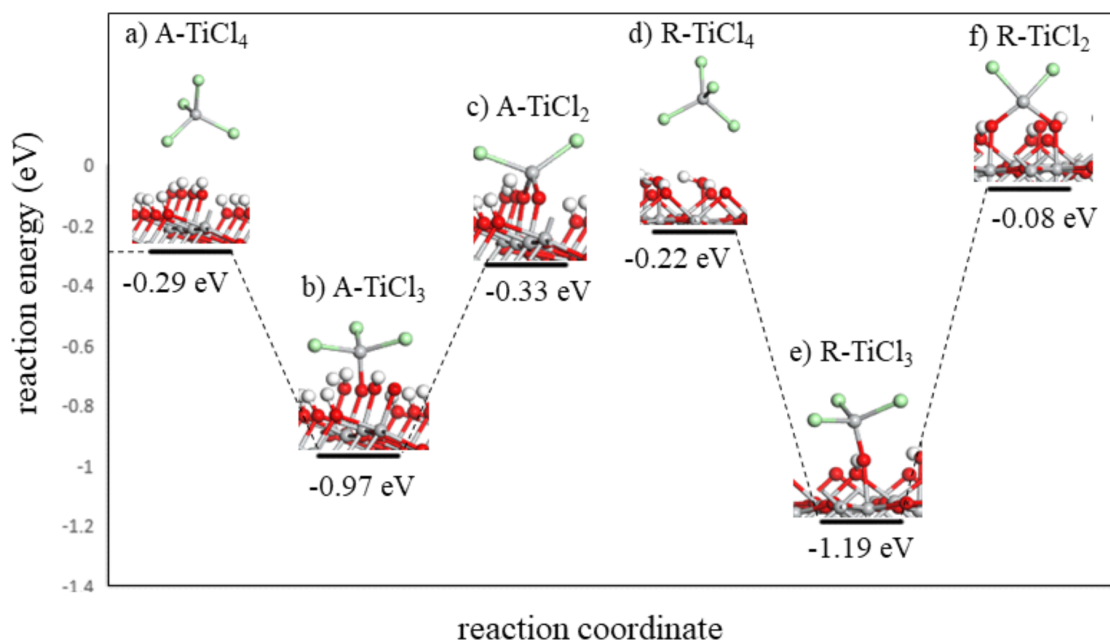


Figure 1: The plotted ligand loss reactions of TiCl_4 on the anatase/rutile TiO_2 surfaces. Optimised atomic structure of a) TiCl_4 interacting with the anatase TiO_2 surface, b) TiCl_3 -terminated anatase TiO_2 surface, c) TiCl_2 -terminated anatase TiO_2 surface, d) TiCl_4 interacting with the rutile TiO_2 surface, e) TiCl_3 -terminated rutile TiO_2 surface and f) TiCl_2 -terminated rutile TiO_2 surface. Light grey: Ti, red: O, green: Cl, white: H. Figure coding is the same for all figures.

TiCl₄ on the anatase TiO₂ surface and rutile TiO₂ surface are presented in Table 1. Energetics for the ligand loss reactions are calculated relative to the first model of TiCl₄ interacting with the surface, and present an overall reaction energy. The overall energy for TiCl₄ to lose Cl ligands and bind on either TiO₂ surface is negative, although there is a notable energy cost for losing the second Cl ligand from surface bound TiCl₃. We do not explore further loss of HCl to give adsorbed TiCl since XPS analysis from previous experimental work showed that chlorine impurities are still present in the film [33], indicating that some Ti–Cl bonds have remained unreacted.

Table 1: Computed adsorption and ligand loss energies of TiCl₄ on anatase/rutile TiO₂ surfaces. In this and all tables in this paper A: anatase TiO₂, R: rutile TiO₂.

Structure	Interaction energy (eV)	Structure	Interaction energy (eV)
A–TiCl ₄	–0.29	R–TiCl ₄	–0.22
A–TiCl ₃	–0.97	R–TiCl ₃	–1.19
A–TiCl ₂	–0.33	R–TiCl ₂	–0.08

The length of the Ti–O bonds formed between TiCl₄ and both TiO₂ surfaces during the first and second ligand loss reactions is presented in Table S1 (Supporting Information File 1). From Table S1 we can see that Ti–O bonds formed between anatase TiO₂ surface and TiCl₄ are about 0.02–0.03 Å shorter when compared to the Ti–O bonds formed between rutile TiO₂ surface and TiCl₄. Generally, shorter Ti–O bonds tend to be stronger, and this can also influence the stability of the system.

In addition to the surface models that result from the adsorption of a single TiCl₄ molecule, in order to investigate the double reaction phenomenon of EG and GL, we have also built models in which two TiCl₄ molecules are adsorbed on the anatase TiO₂ and rutile TiO₂ surfaces. Calculated energies for the adsorption of the second TiCl₄ molecule are –0.81 eV on the anatase TiO₂ surface and –0.03 eV on the rutile TiO₂ surface. This difference may arise from the higher stability of rutile TiO₂ compared to anatase TiO₂. The resulting surfaces after the adsorption of the second TiCl₄ molecule are terminated with two TiCl₃ species, anatase–2TiCl₃ and rutile–2TiCl₃, and the distance between the Ti atoms of the two TiCl₃ species is 6.0 Å on the anatase TiO₂ surface and 6.9 Å on rutile TiO₂ surface.

Reactions between organic precursors and TiCl₃/TiCl₂-terminated anatase/rutile TiO₂ surface

With these post-TiCl₄ pulse models of anatase TiO₂ and rutile TiO₂ available, the interactions between the TiO₂–TiCl₃ and

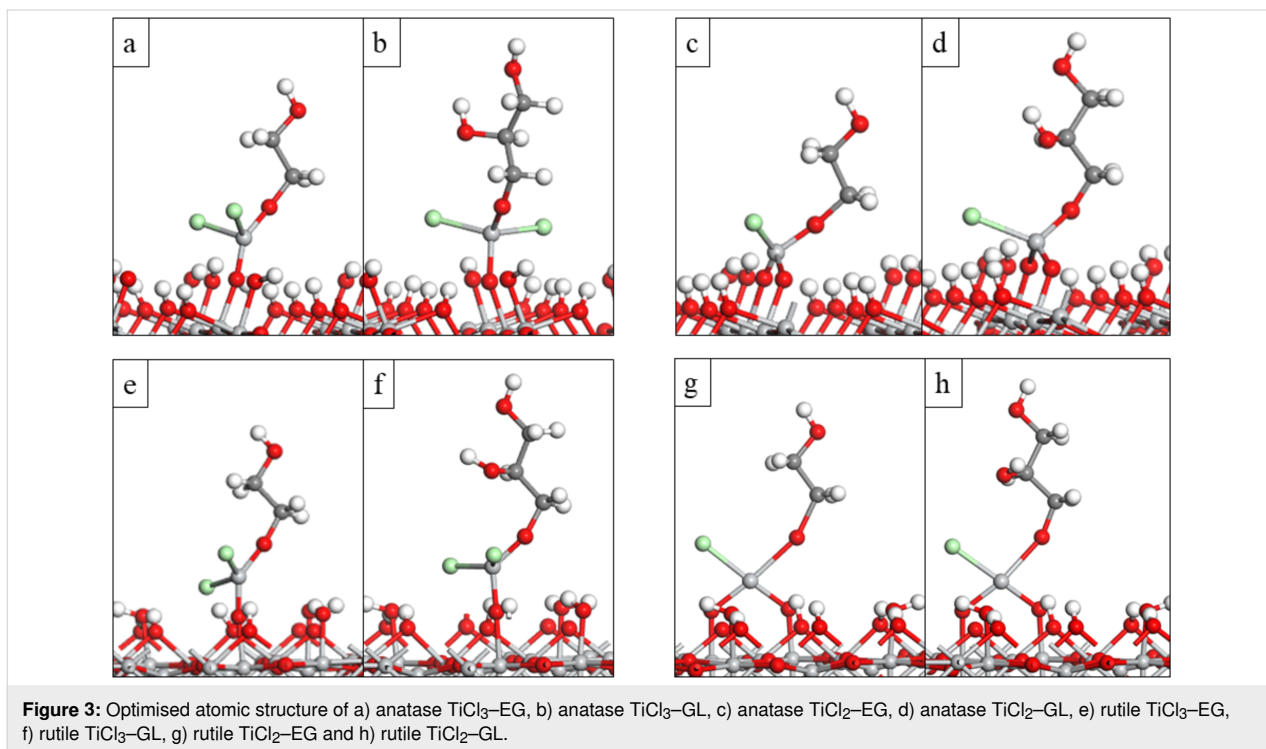
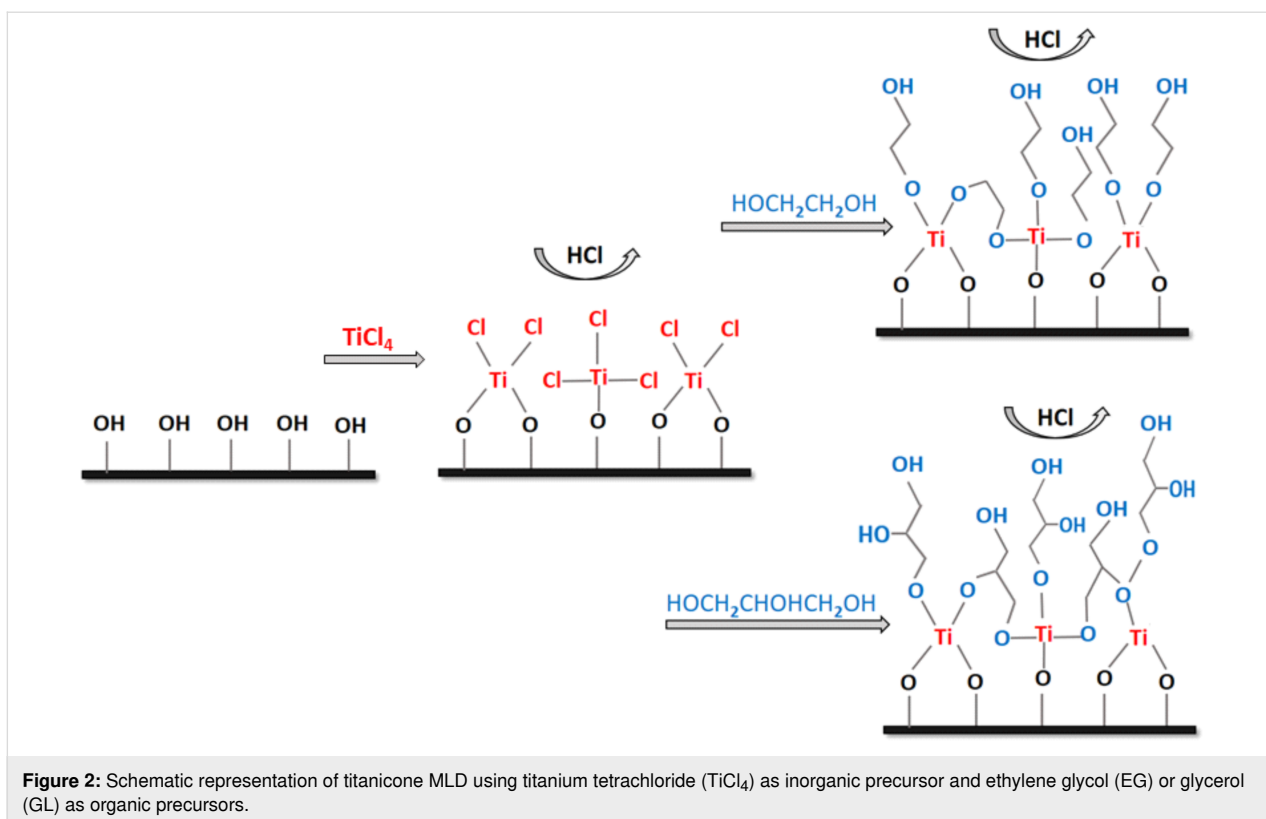
TiO₂–TiCl₂ species and the organic precursors are investigated by analysing the formation of MLD products with EG and GL. Reactions with EG and GL involve the transfer of one proton from a terminal OH group of the organic molecule to a Cl ligand of TiCl₃/TiCl₂ to release a HCl molecule as by-product and form one new Ti–O bond between the TiCl₃/TiCl₂ species and the organic molecules. A schematic illustration of titania-cone MLD films based on the reactions between the hydroxylated surface and TiCl₄ and the reactions between the TiCl₃/TiCl₂ surface species with EG and GL is presented in Figure 2. The resulting atomic structures of the MLD reaction products with EG and GL are shown in Figure 3.

The overall energy change for the reactions between the TiCl₃/TiCl₂-terminated anatase TiO₂ and rutile TiO₂ surfaces with EG and GL is presented in Table 2 and these results show that the calculated energies for the reactions between the TiCl₃-terminated surfaces with EG and GL, associated with the release of one HCl molecule, are exothermic and therefore favourable. There are also clear differences when EG and GL bind with TiCl₃ and TiCl₂-terminated TiO₂ surfaces. The calculated energies for the reactions between the TiCl₂-terminated surfaces with EG and GL, associated with the release of one HCl molecule, are endothermic, meaning that these reactions are not favourable. We found a similar difference for the reaction of TiCl₃/TiCl₂ with aromatic precursors [42].

Table 2: Computed interaction energies of EG and GL on the TiCl₃/TiCl₂-terminated anatase/rutile TiO₂ surface.

Structure	Interaction energy (eV)	Structure	Interaction energy (eV)
A–TiCl ₃ –EG	–0.79	R–TiCl ₃ –EG	–0.96
A–TiCl ₃ –GL	–0.66	R–TiCl ₃ –GL	–1.77
A–TiCl ₂ –EG	0.08	R–TiCl ₂ –EG	0.49
A–TiCl ₂ –GL	0.15	R–TiCl ₂ –GL	0.81

We also consider the Ti–O distances formed between the EG and GL with TiCl₃/TiCl₂ species as well as changes in the Ti-surface distances between TiCl₃ and TiCl₂ and surface oxygens after the introduction of EG and GL, Table S2 (Supporting Information File 1). We notice that Ti–O bonds formed between EG and GL and the TiCl₃ terminated anatase TiO₂ and rutile TiO₂ surfaces are 0.02 Å shorter compared to Ti–O bonds formed between EG and GL with the TiCl₂ terminated anatase TiO₂ and rutile TiO₂ surfaces. Ti–O distances between TiCl₄ and the surface oxygens also change after the introduction of EG and GL. After the introduction of EG and GL, Ti–O bonds to the surface are lengthen for 0.02 Å to 0.03 Å in the TiCl₃ terminated anatase TiO₂ and rutile TiO₂ surfaces and 0.02 Å



to 0.07 Å in the TiCl_2 terminated anatase TiO_2 and rutile TiO_2 surfaces. As DFT results suggest that the formation of Ti–O bonds between EG and GL and the TiCl_2 species on the anatase

TiO_2 and rutile TiO_2 surfaces is energetically unfavourable, in the next calculations we exclude the TiCl_2 terminated surfaces.

Comparison of upright and flat-lying reactions of ethylene glycol (EG) and glycerol (GL) on the TiCl_3 -terminated anatase/rutile TiO_2 surface

Double reactions of EG and GL are investigated by examining the interactions between the TiO_2 surface terminated with 2TiCl_3 and 2TiCl_3 with EG and GL in the upright configuration and in the flat configuration. In the upright configuration, EG and GL bind to Ti sites through one terminal OH group and one HCl molecule is released. In the flat configuration, EG and GL bind through two terminal OH groups with two neighbouring Ti sites and two HCl molecules are released.

Optimised atomic structures of the MLD reaction products of TiCl_3 -terminated anatase TiO_2 and rutile TiO_2 surfaces with upright and flat lying EG and GL are shown in Figure 4. The computed energies when EG and GL bind with one Ti site in the upright configuration and with two Ti sites in the flat lying

configuration are shown in Table 3. The calculated energy for the upright configuration of EG and GL is calculated with reference to the energy of the adsorbed Ti precursor on the relevant surface, while the calculated energy for the flat configuration of EG and GL is with reference to the energy of the corresponding upright structure. This allows us to assess if the double reactions of EG and GL are thermodynamically favourable when reacting with TiCl_3 on anatase TiO_2 and rutile TiO_2 surfaces.

From Table 3 we see that the EG and GL molecules interact favourably in an upright configuration at the 2TiCl_3 -terminated anatase TiO_2 surface. However, there is a further gain in energy of -0.55 eV for EG and -0.33 eV for GL when the molecules change their configuration from upright to flat lying, and a second HCl molecule is released. These energies show that EG and GL could also undergo double reactions on the anatase TiO_2 surface, although for GL this difference in energy is smaller than for EG.

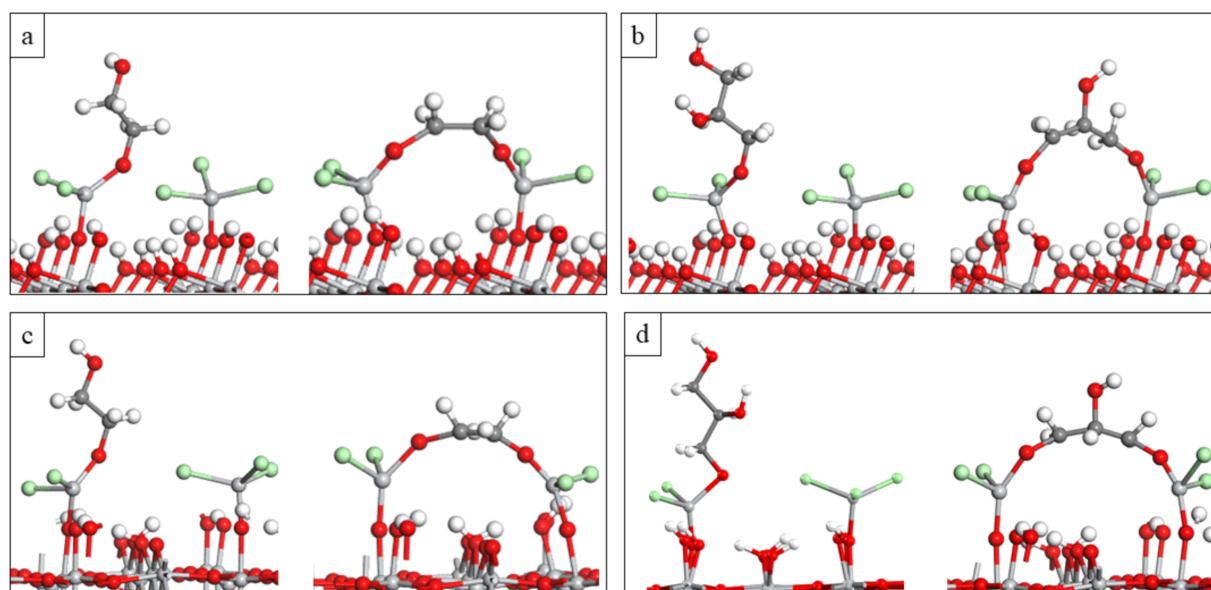


Figure 4: Optimised atomic structure of a) upright and flat EG on the anatase 2TiCl_3 , b) upright and flat GL on the anatase 2TiCl_3 , c) upright and flat EG on the rutile 2TiCl_3 , d) upright and flat GL on the rutile 2TiCl_3 .

Table 3: Computed interaction energy of EG and GL in the upright configuration with TiCl_3 -terminated anatase/rutile TiO_2 surface. The energy change between the flat (double reaction) and upright configuration is also presented.

Structure	Interaction energy (eV)	Structure	Interaction energy (eV)
A- 2TiCl_3	-0.81	R- 2TiCl_3	-0.03
A- 2TiCl_3 -EG-up	-0.72	R- 2TiCl_3 -EG-up	-0.46
A- 2TiCl_3 -EG-flat	-0.55	R- 2TiCl_3 -EG-flat	0.34
A- 2TiCl_3 -GL-up	-0.63	R- 2TiCl_3 -GL-up	-0.36
A- 2TiCl_3 -GL-flat	-0.33	R- 2TiCl_3 -GL-flat	0.33

Similar to Al_2O_3 , this phenomenon for EG will reduce the number of OH sites on the surface and this should make the growth of TiCl_4 –EG films less favourable. However, despite the reduction of OH groups on the surface, terminal oxygen sites of the flat EG can also serve as active sites and they can bind with other TiCl_4 molecules in the following cycle, similar to TMA–EG alucones [39]. The GL molecule is a triol with three OH active groups, so even in the case of double reactions for GL the third OH group is available for further reactions.

The EG and GL molecules interact also favourably in an upright configuration with the 2TiCl_3 –terminated rutile TiO_2 surface, while for their flat lying configuration the overall energy change is slightly endothermic. This shows that in a rutile surface EG and GL could prefer to orient in an upright configuration. For the 2TiCl_3 –EG model, the distance between Ti and O in the $\text{Ti–O–CH}_2\text{CH}_2\text{–O}$ fragment that is formed during one MLD cycle (EG in the upright configuration) is ≈ 4.97 Å. This distance is similar with the achieved growth rate of ≈ 4.5 Å/cycle to 6 Å/cycle for TiCl_4 –EG films in a temperature range of 100–120 °C on a SiO_2 membrane [27] and ≈ 4.6 Å/cycle at 90 °C in Si(100) wafers [30]. We note the relatively low temperature of the titanocene deposition in refs. [27,30] which may prevent the double reaction with EG.

For the TiCl_3 –GL model, the distance between Ti and O in the $\text{Ti–O–CH}_2\text{CH}_2\text{OHCH}_2\text{–O}$ fragment (GL in the upright configuration) is ≈ 6.26 Å. However, the achieved growth rate of TiCl_4 –GL films in experimental work is much smaller, 2.8 Å/cycle at 130 °C to 2.1 Å/cycle at 210 °C when deposited in Si wafers [30] and 2.2 Å/cycle at 150 °C deposited again in Si wafers in another study [31]. The distance between the surface and the available OH group of the flat GL is 4.2 Å and this distance is close to the measured growth per cycle of TiCl_3 –GL films in experimental work. Although the lower growth per cycle of TiCl_3 –GL films achieved in these experimental studies are most consistent with a flat lying orientation of GL when deposited on Si surfaces, DFT shows that the desired upright orientation of GL could be energetically favourable on a rutile TiO_2 surface and this provides motivation to develop a lower temperature rutile TiO_2 / TiCl_4 –GL process where higher growth per cycle could be achieved. We note that the experimental data are not immediately comparable since different deposition temperatures are used, with significantly higher temperatures for the GL process compared to the EG process which may favour the flat-lying configuration.

In summary, DFT calculations show that while in an anatase TiO_2 surface the organic molecules EG and GL can orient in both configurations, upright and lying flat, in the rutile TiO_2 surface these molecules could prefer more the upright configura-

tion, although the flat-lying configuration may also be stabilised. This indicates that the surface can also have an important role on the orientation of the organic species.

The Ti–O distances to the EG and GL in the upright and flat lying configurations are presented in Table S3 (Supporting Information File 1). The computed distances show that the Ti–O bond to the molecules does not change significantly when EG and GL change their configuration from upright to lying flat on the anatase TiO_2 surface (0.01 Å longer). On the other hand, on rutile, the Ti–O bonds to the organic molecules in the flat lying configuration are 0.03 Å to 0.06 Å longer compared to Ti–O bonds of these molecules in the upright configuration. The increment of these bonds when EG and GL change their configuration from upright to lying flat on the rutile TiO_2 surface also indicates the lower stability of these molecules in the flat configuration on the TiCl_3 terminated rutile TiO_2 surface.

For the upright EG and GL on the anatase TiO_2 surface, the Ti–O distance between Ti of TiCl_4 and the oxygen atom of the anatase TiO_2 surface is 1.77 Å. This distance decreases to 1.75 Å when EG and GL change their configuration to lying flat. For EG in the upright and flat lying configuration on the rutile TiO_2 surface the Ti–O distance between Ti of TiCl_4 and the oxygen atom is 1.77 Å. For GL in the upright and flat lying configuration on the rutile TiO_2 surface this distance is 1.76 Å.

Surface models of $\text{Ti}(\text{DMA})_3$, $\text{Ti}(\text{DMA})_2$ and TiDMA –terminated anatase/rutile TiO_2 and Al_2O_3 after the $\text{Ti}(\text{DMA})_4$ pulse

$\text{Ti}(\text{DMA})_4$ is another Ti precursor that has been used for the deposition of TiO_2 [35] and TiN [36] ALD films and titanocene MLD films [33]. $\text{Ti}(\text{DMA})_4$ is a metalorganic precursor containing Ti–N bonds to the organic ligands, dimethylamino (DMA , $\text{N}(\text{CH}_3)_2$), and with a much larger molecular size when compared to TiCl_4 . It offers some advantages as a precursor, including the noncorrosive nature of by-products of ligand elimination, higher reactivity due to the weak Me–N bonds and good thermal stability [38]. We performed DFT calculations to study the feasibility of the growth of titanocene films using $\text{Ti}(\text{DMA})_4$ and EG or GL as MLD precursors and to investigate the molecular mechanism behind the possible growth. The hydroxylated anatase TiO_2 surface, hydroxylated rutile TiO_2 surface and hydroxylated Al_2O_3 surface were selected as surface models.

In the first calculations, we calculate the reactivity of the $\text{Ti}(\text{DMA})_4$ precursor towards the selected surfaces. The calculated interaction energies on the anatase TiO_2 , rutile TiO_2 and the Al_2O_3 surfaces are -0.88 eV, -0.74 eV and -1.47 eV, re-

spectively. Thus, $\text{Ti}(\text{DMA})_4$ adsorbs favourably on the three oxide surfaces.

Next, the thermodynamics of the first, second and third ligand loss reactions of the $\text{Ti}(\text{DMA})_4$ precursor are examined. These reactions take place with a proton transfer from surface OH groups to the DMA ligands of $\text{Ti}(\text{DMA})_4$ to form protonated molecules, H-DMA, released as by-products and the formation of new Ti–O bonds between $\text{Ti}(\text{DMA})_4$ and oxygen atoms on the surface. After the third ligand loss reaction, Ti of $\text{Ti}(\text{DMA})_4$ is bonded to three surface oxygens and to one DMA ligand that can exchange with one organic molecule during the organic precursor pulse. The coordination number of Ti of the $\text{Ti}(\text{DMA})_4$ molecule is four and remains unchanged during the ligand loss reactions.

The ligand loss reaction mechanism of $\text{Ti}(\text{DMA})_4$ is presented in Figure 5. Optimized atomic structures of the anatase TiO_2 , rutile TiO_2 and the Al_2O_3 surfaces interacting with $\text{Ti}(\text{DMA})_4$ and after the elimination of the first, second and third ligand of $\text{Ti}(\text{DMA})_4$ are presented in Figure 6. The computed interaction and ligand loss energies of $\text{Ti}(\text{DMA})_4$ are presented in Table 4. The energies for the ligand loss reactions are calculated relative to the first model of $\text{Ti}(\text{DMA})_4$ interacting with the surface, and present an overall reaction energy. Ligand loss energies show that the overall energy for $\text{Ti}(\text{DMA})_4$ to lose DMA ligands and bind on either TiO_2 surface or Al_2O_3 surface is favourable.

When we compare these energies to those calculated for TiCl_4 interacting and binding on the same selected surfaces, we see that $\text{Ti}(\text{DMA})_4$ interacts and binds more favourably with the surfaces as the calculated reaction energies are much larger. This is consistent with bond dissociation energy values for the breakage of the Ti–Cl and Ti–N bonds (494 kJ/mol and

464 kJ/mol, respectively) which show that the Ti–Cl bond is stronger and thus more difficult to break.

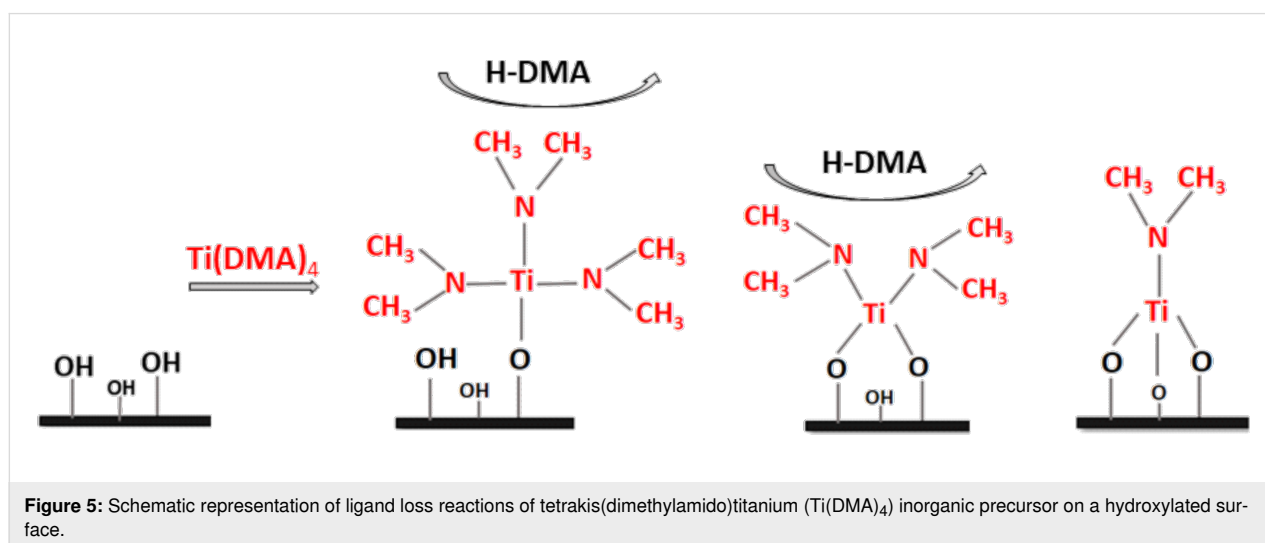
The overall reaction energy which includes the interaction of $\text{Ti}(\text{DMA})_4$ with the surface and the three ligand loss reactions is the largest on the rutile TiO_2 surface, -2.53 eV, which is -0.53 eV larger when compared to the Al_2O_3 surface and -1.73 eV larger when compared to the anatase TiO_2 surface.

The new Ti–O bonds of $\text{Ti}(\text{DMA})_4$ to the Al_2O_3 surface are 0.03 – 0.08 Å shorter, when compared to those formed between $\text{Ti}(\text{DMA})_4$ and the anatase TiO_2 surface or rutile TiO_2 surface, Table S4 (Supporting Information File 1).

In order to investigate double reactions of EG and GL we built also the surface models after the adsorption of two $\text{Ti}(\text{DMA})_4$ molecules. The reactions when a second $\text{Ti}(\text{DMA})_4$ molecule is adsorbed are associated with the release of three H-DMA molecules as by-products and the surfaces are left covered with two TiDMA species, anatase-2TiDMA, rutile-2TiDMA and Al_2O_3 -2TiDMA. Calculated energetics for the adsorption of the second $\text{Ti}(\text{DMA})_4$ precursors are -1.05 eV for the anatase TiO_2 surface, -1.29 eV for the rutile TiO_2 surface, -2.06 eV for the Al_2O_3 surface. The distance between Ti atoms of the two TiDMA species is 7.2 Å on the anatase TiO_2 surface and rutile TiO_2 surface and 7.1 Å on the Al_2O_3 surface.

Reactions between organic precursors and TiDMA-terminated anatase/rutile TiO_2 and Al_2O_3 surfaces

Next, we analysed MLD reactions using EG and GL as organic reactants where the organic molecules are modelled in both upright and flat lying configurations. Similar to the reaction between TiCl_4 and EG or GL, the reaction between $\text{Ti}(\text{DMA})_4$



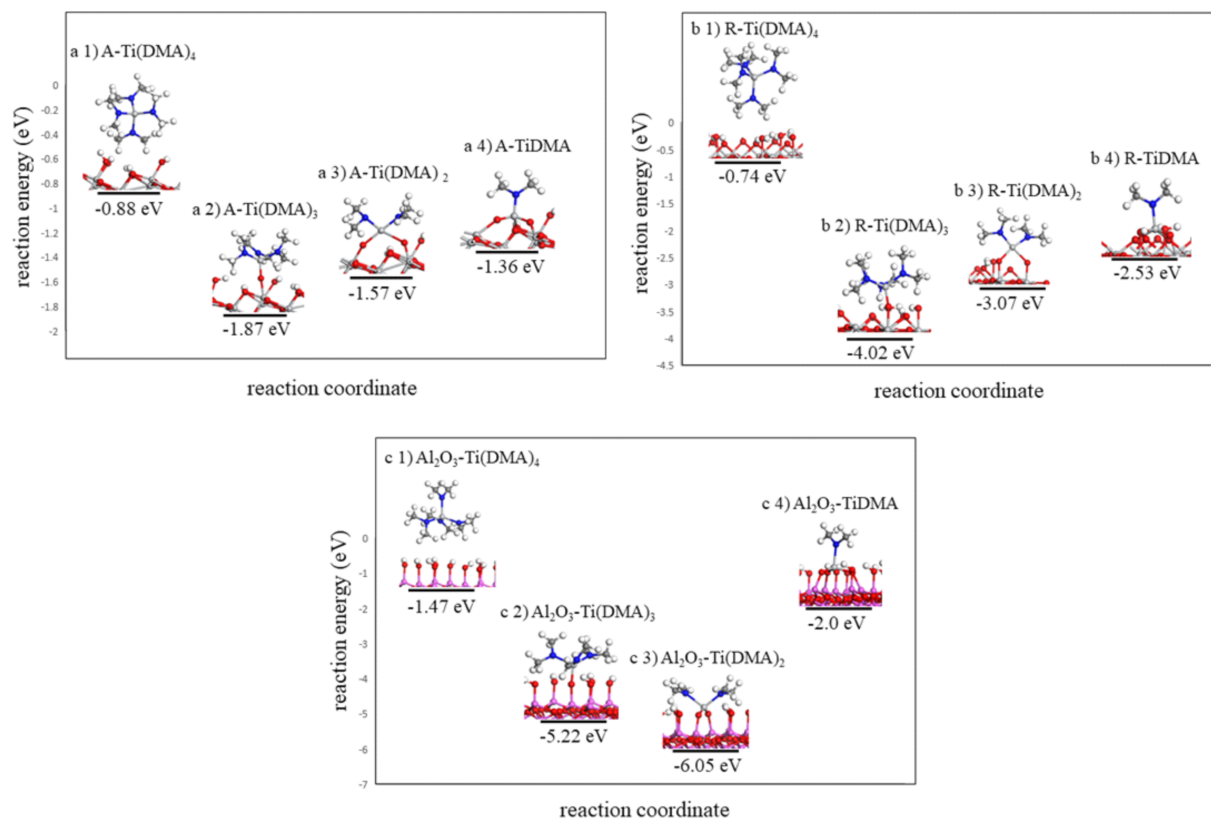


Figure 6: The plotted ligand loss reactions of $\text{Ti}(\text{DMA})_4$ on the anatase/rutile TiO_2 surface and Al_2O_3 surface. Optimised atomic structure of a1) $\text{Ti}(\text{DMA})_4$ interacting with the anatase TiO_2 surface, a2) $\text{Ti}(\text{DMA})_3$ -terminated anatase TiO_2 surface, a3) $\text{Ti}(\text{DMA})_2$ -terminated anatase TiO_2 surface, a4) TiDMA -terminated anatase TiO_2 surface, b1) $\text{Ti}(\text{DMA})_4$ interacting with the rutile TiO_2 surface, b2) $\text{Ti}(\text{DMA})_3$ -terminated rutile TiO_2 surface, b3) $\text{Ti}(\text{DMA})_2$ -terminated rutile TiO_2 surface, b4) TiDMA -terminated rutile TiO_2 surface, c1) $\text{Ti}(\text{DMA})_4$ -interacting with the Al_2O_3 surface, c2) $\text{Ti}(\text{DMA})_3$ -terminated Al_2O_3 surface, c3) $\text{Ti}(\text{DMA})_2$ -terminated Al_2O_3 surface and c4) TiDMA -terminated Al_2O_3 surface. Dark grey: C, blue: N. Figure coding is the same for all figures.

Table 4: Computed adsorption and ligand loss energies of $\text{Ti}(\text{DMA})_4$ on the anatase/rutile TiO_2 surface and Al_2O_3 surface.

Structure	Interaction energy (eV)	Structure	Interaction energy (eV)	Structure	Interaction energy (eV)
$\text{A-Ti}(\text{DMA})_4$	-0.88	$\text{R-Ti}(\text{DMA})_4$	-0.74	$\text{Al}_2\text{O}_3\text{-Ti}(\text{DMA})_4$	-1.47
$\text{A-Ti}(\text{DMA})_3$	-1.87	$\text{R-Ti}(\text{DMA})_3$	-4.02	$\text{Al}_2\text{O}_3\text{-Ti}(\text{DMA})_3$	-5.22
$\text{A-Ti}(\text{DMA})_2$	-1.57	$\text{R-Ti}(\text{DMA})_2$	-3.07	$\text{Al}_2\text{O}_3\text{-Ti}(\text{DMA})_2$	-6.05
A-TiDMA	-1.36	R-TiDMA	-2.53	$\text{Al}_2\text{O}_3\text{-TiDMA}$	-2

and EG or GL requires the transfer of one proton from the terminal OH group of the organic molecule to one DMA ligand of $\text{Ti}(\text{DMA})_4$ to release a H-DMA molecule as a by-product coupled with the formation of a new Ti-O bond between Ti and the organic molecule. Figure 7 shows the optimized atomic structures after the introduction of one EG and GL molecule and the loss of one H-DMA by-product.

The overall energy change for the reactions between the TiDMA -terminated anatase TiO_2 , rutile TiO_2 and Al_2O_3 surfaces with EG and GL is presented in Table 5. Calculated energies show that the Ti-O bond formation with EG and GL, with release of H-DMA, is favourable on all surfaces. The overall interaction energy is largest on anatase TiO_2 followed by rutile TiO_2 .

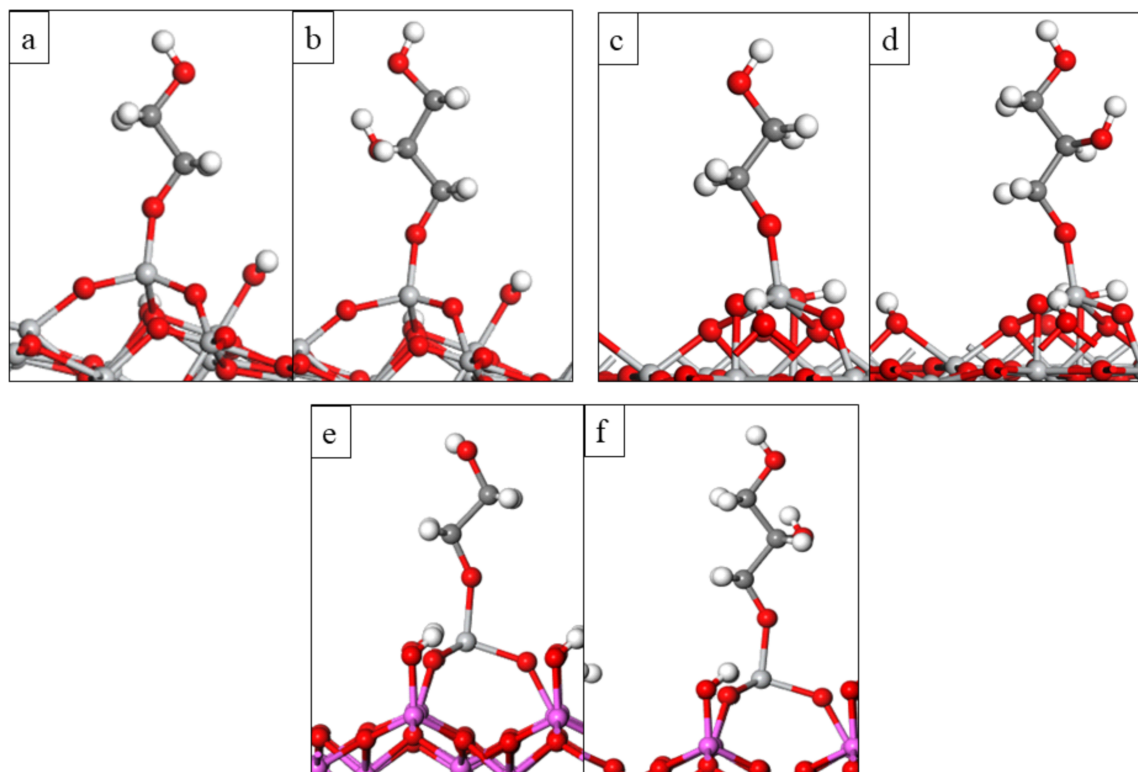


Figure 7: Optimised atomic structure of a) anatase TiDMA-EG, b) anatase TiDMA-GL, c) rutile TiDMA-EG, d) rutile TiDMA-GL, e) Al₂O₃ TiDMA-EG and f) Al₂O₃ TiDMA-GL.

Table 5: Computed interaction energies of EG and GL on the TiDMA-terminated anatase/rutile TiO₂ and Al₂O₃ surfaces.

Structure	Interaction energy (eV)	Structure	Interaction energy (eV)	Structure	Interaction energy (eV)
A-TiDMA-EG	−3.42	R-TiDMA-EG	−2.98	Al ₂ O ₃ -TiDMA-EG	−1.75
A-TiDMA-GL	−3.31	R-TiDMA-GL	−2.89	Al ₂ O ₃ -TiDMA-GL	−1.60

Ti–O distances between Ti and the organic molecules are shown in Table S5 (Supporting Information File 1). Ti–O bonds formed between EG and GL with the TiDMA-terminated anatase TiO₂ and rutile TiO₂ surfaces are 0.06 Å to 0.08 Å shorter when compared to those formed between the EG and GL and the TiDMA-terminated Al₂O₃ surface, which is consistent with the more favourable interaction energies.

We also examined the change in the Ti–O distances to the surface oxygens after the introduction of the EG and GL, and these are presented in Table S6 (Supporting Information File 1). The computed Ti–O distances show that after the introduction of the EG and GL Ti–O bonds to the surface oxygens undergo negligible changes, indicating that the EG and GL will not affect the stability of the systems.

Comparison of upright and flat-lying reactions of ethylene glycol (EG) and glycerol (GL) on the 2TiDMA-terminated anatase/rutile TiO₂ and Al₂O₃ surfaces

We investigated also the double reactions of EG and GL on the anatase-2TiDMA surface, rutile-2TiDMA surface and Al₂O₃-2TiDMA, where EG and GL are modelled in the upright and flat lying configurations. In the upright configuration organic molecules bind to Ti sites through one terminal OH group and one H–DMA molecule is released while in the flat configuration organic molecules will bind through two terminal OH groups with two neighbouring Ti sites and two H–DMA molecules are released. Figure 8 shows the optimised atomic structures of the MLD reaction products of 2TiDMA-termi-

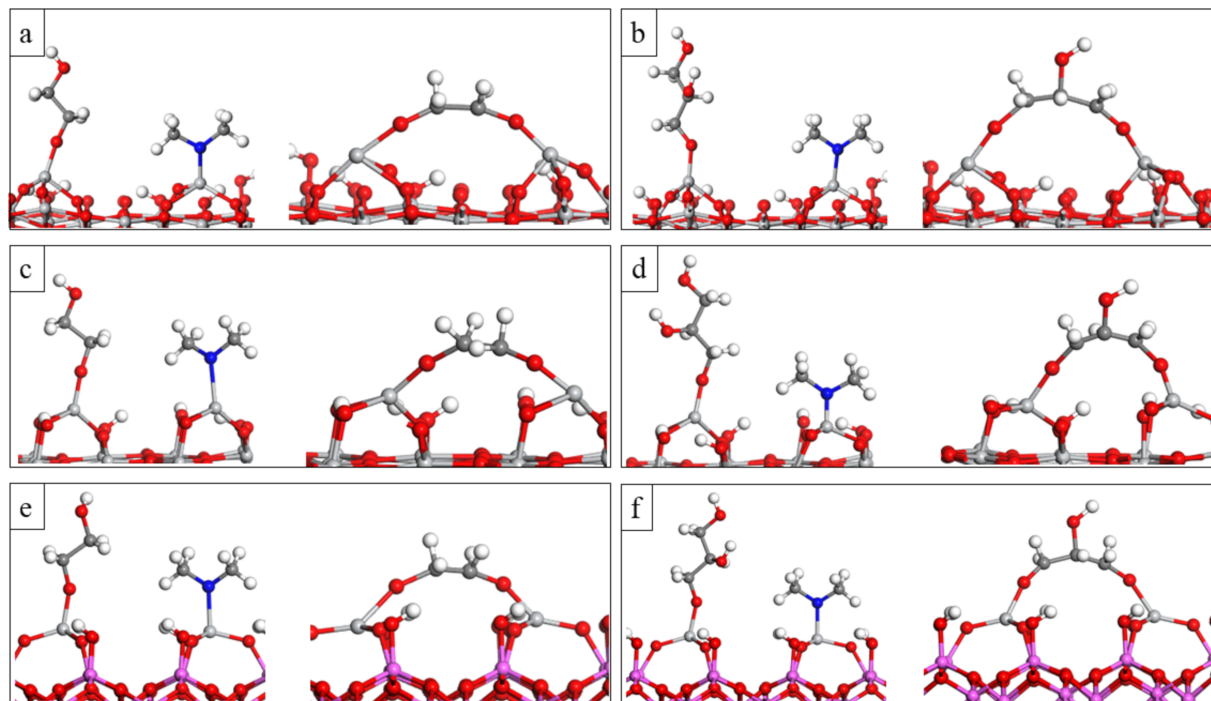


Figure 8: Optimised atomic structure of a) upright and flat EG on the anatase-2TiDMA, b) upright and flat GL on the anatase-2TiDMA, c) upright and flat EG on the rutile-2TiDMA, d) upright and flat GL on the rutile-2TiDMA, e) upright and flat EG on the Al_2O_3 -2TiDMA and f) upright and flat GL on the Al_2O_3 -2TiDMA.

nated anatase TiO_2 , rutile TiO_2 and Al_2O_3 surfaces with the upright and flat lying EG and GL. Calculated energetics for the reactions of EG and GL in the upright and flat laying configuration with the 2TiDMA-terminated surfaces are shown in Table 6.

Calculated energetics for the reactions between upright EG and GL with the 2TiDMA-terminated anatase TiO_2 , rutile TiO_2 and Al_2O_3 surfaces are negative, meaning that the reactions are exothermic and therefore favourable. The energies for the reactions between the upright EG and GL and the 2TiDMA-terminated

anatase TiO_2 , rutile TiO_2 and Al_2O_3 surfaces are calculated relative to the energy for the adsorption of two $\text{Ti}(\text{DMA})_4$ molecules on the relevant surface. The energies for the flat configuration are calculated relative to the upright structures of EG and GL. A negative energy gain was calculated for all reactions when EG and GL change their configuration from upright to flat lying and one H-DMA molecule is released, regardless of the surface.

Calculated energetics show that while the EG and GL can bind to the Ti sites via formation of Ti–O bonds and loss of

Table 6: Computed interaction energies of EG and GL in the upright configuration with the 2TiDMA-terminated anatase/rutile TiO_2 and Al_2O_3 surfaces. The energy change between the flat (double reaction) and upright configuration is also presented.

Structure	Interaction energy (eV)	Structure	Interaction energy (eV)	Structure	Interaction energy (eV)
A-2TiDMA	–1.05	R-2TiDMA	–1.29	Al_2O_3 -2TiDMA	–2.06
A-2TiDMA-EG-up	–1.44	R-2TiDMA-EG-up	–1.65	Al_2O_3 -2TiDMA-EG-up	–1.73
A-2TiDMA-EG-flat	–0.32	R-2TiDMA-EG-flat	–0.20	Al_2O_3 -2TiDMA-EG-flat	–1.6
A-2TiDMA-GL-up	–1.40	R-2TiDMA-GL-up	–1.61	Al_2O_3 -2TiDMA-GL-up	–1.81
A-2TiDMA-GL-flat	–0.68	R-2TiDMA-GL-flat	–0.90	Al_2O_3 -2TiDMA-GL-flat	–1.3

H-DMA, it is most favourable for the organic precursors to lie flat and create the double reactions through the two terminal OH groups. This phenomenon removes all active sites for EG and the growth will be less favourable while GL has an extra OH group compared to EG which reacts with $\text{Ti}(\text{DMA})_4$ in the next cycle and the growth proceeds.

Calculations energetics suggest that organic molecules EG and GL combined with $\text{Ti}(\text{DMA})_4$ in an anatase TiO_2 , rutile TiO_2 and Al_2O_3 surface behave similarly as when combined with $\text{Ti}(\text{DMA})_4$ on a Si substrate [33]. Experimental data in ref [33] show that for $\text{Ti}(\text{DMA})_4$ -EG films deposited on a Si substrate in a temperature range of 80–150 °C the growth starts but it stops after 5–10 cycles, and this most probably due to the favourable double reactions of EG molecules with the Ti species. For $\text{Ti}(\text{DMA})_4$ -GL films the growth proceeds even when the molecule reacts twice with the surface due to the extra OH group which reacts with $\text{Ti}(\text{DMA})_4$ in the next cycle. However, although the growth of $\text{Ti}(\text{DMA})_4$ -GL films proceeds, these double reactions lead to small GPCs, 0.9 Å/cycle to 0.2 Å/cycle when deposited in a Si substrate in a temperature range of 80–160 °C. The stability and GPC of the $\text{Ti}(\text{DMA})_4$ -GL-based film may also depend on the strength of interaction with GL, which is less favourable than with EG.

The Ti–O distances to the EG and GL molecules in the upright and flat lying configurations are presented in Table S7 (Supporting Information File 1). The computed Ti–O bonds to the organic molecules in the anatase TiO_2 and rutile TiO_2 surfaces are lengthen from 0.05 Å to 0.25 Å when EG and GL change their configuration from upright to lying flat.

In summary, DFT calculations show that the chemistry of the organic molecules will depend on the inorganic precursor used and on the surface onto which the films are deposited. We see that EG and GL prefer to lie flat when combined with $\text{Ti}(\text{DMA})_4$ on the anatase TiO_2 , rutile TiO_2 and Al_2O_3 surfaces and with TiCl_4 in an anatase TiO_2 surface but they do not prefer to lie flat when combined with TiCl_4 on a rutile TiO_2 surface. The interactions with TiCl_4 precursor are also less favourable than with $\text{Ti}(\text{DMA})_4$, partially explained by the strong Ti–Cl bond compared to Ti–N.

Conclusion

In this study, we used first principles density functional theory (DFT) to investigate the atomistic mechanism of the growth of titanium containing hybrid films known as “titanicones” deposited by MLD. We investigated in detail the chemistry of the MLD process between the TiCl_4 or $\text{Ti}(\text{DMA})_4$ inorganic precursors and EG or GL organic molecules. We used anatase TiO_2 , rutile TiO_2 and Al_2O_3 surface models.

Through DFT we calculated the reactivity of TiCl_4 or $\text{Ti}(\text{DMA})_4$ inorganic precursors towards the selected surfaces and towards EG and GL organic molecules and predicted the preferred orientation of these organic molecules when combined with TiCl_4 and $\text{Ti}(\text{DMA})_4$ in an anatase TiO_2 , rutile TiO_2 and Al_2O_3 surface.

Calculated energetics show that while TiCl_4 interacts and binds favourably with the anatase TiO_2 and rutile TiO_2 surfaces via Ti–O bonds and release of HCl, the interaction with the Al_2O_3 surface is not favourable. Ligand loss reactions of TiCl_4 on the anatase TiO_2 and rutile TiO_2 surface are favourable, although there is a notable energy cost for losing the second Cl ligand from surface bound TiCl_3 . Double reactions of EG and GL molecules with TiCl_3 species are also closely explored. DFT findings show that these molecules can bind with TiCl_3 species in the anatase TiO_2 surface in the upright configuration with one terminal OH group and in the flat configuration with two terminal OH groups. In the rutile TiO_2 surface on the other hand, the preferred orientation of EG and GL molecules is upright. Therefore, we consider the rutile TiO_2 surface as a suitable surface for the growth of TiCl_4 -EG and TiCl_4 -GL titanicones films where the desired GPCs could be achieved.

DFT calculations show that $\text{Ti}(\text{DMA})_4$ also interacts and binds favourably with the anatase TiO_2 , rutile TiO_2 and the Al_2O_3 surface via Ti–O bonds. The ligand loss reactions of $\text{Ti}(\text{DMA})_4$ are associated with the release of H-DMA ($\text{H}-\text{N}(\text{CH}_3)_2$) by-products. A higher reactivity of $\text{Ti}(\text{DMA})_4$ compared to TiCl_4 was calculated and this is most probably due to the stronger Ti–Cl bonds present in TiCl_4 compared to Ti–N bonds present in $\text{Ti}(\text{DMA})_4$. We show that EG and GL bind favourably with Ti species of $\text{Ti}(\text{DMA})_4$ via Ti–O bonds and release of H-DMA by-products. However, reaction energetics indicate that these molecules can lie flat and create the unwanted double reactions through the reaction of the two terminal OH groups with the surface fragments. For EG this phenomenon removes active OH groups from the surface and the growth will be less favourable while for GL the third OH group is available and growth proceeds. This analysis supports experimental data on $\text{Ti}(\text{DMA})_4$ -EG and $\text{Ti}(\text{DMA})_4$ -GL film growth and clarifies why for the $\text{Ti}(\text{DMA})_4$ -EG process, the growth stops after 5–10 cycles while for the $\text{Ti}(\text{DMA})_4$ -GL process, the growth proceeds [33].

Temperature is a very important factor for the successful deposition of MLD films. It significantly affects the chemistry between the MLD precursors and especially the behaviour of the organic molecules in the hybrid films. Therefore, we consider this aspect very interesting and worthy of investigating in future work.

Supporting Information

Supporting Information File 1

Additional data on the geometry of the structures.

[<https://www.beilstein-journals.org/bjnano/content/supplementary/2190-4286-13-103-S1.pdf>]

Funding

We acknowledge support from Science Foundation Ireland for computational resources at Tyndall National Institute. We acknowledge support from H2020 MSCA-ITN Network HYCOAT, Grant Number 765378 and from Science Foundation Ireland, through the SFI-NSFC Partnership Program, project NITRALD 17/NSFC/5279

ORCID® iDs

Arbresha Muriqi - <https://orcid.org/0000-0002-2392-0278>

Michael Nolan - <https://orcid.org/0000-0002-5224-8580>

Preprint

A non-peer-reviewed version of this article has been previously published as a preprint:

<https://chemrxiv.org/engage/chemrxiv/article-details/62b1d84558b3d6054f58b4c3>

References

- Sundberg, P.; Karppinen, M. *Beilstein J. Nanotechnol.* **2014**, *5*, 1104–1136. doi:10.3762/bjnano.5.123
- Meng, X. *J. Mater. Chem. A* **2017**, *5*, 18326–18378. doi:10.1039/c7ta04449f
- Gregorczyk, K.; Knez, M. *Prog. Mater. Sci.* **2016**, *75*, 1–37. doi:10.1016/j.pmatsci.2015.06.004
- Zhao, Y.; Sun, X. *ACS Energy Lett.* **2018**, *3*, 899–914. doi:10.1021/acsenergylett.8b00145
- Leskelä, M.; Ritala, M. *Thin Solid Films* **2002**, *409*, 138–146. doi:10.1016/s0040-6090(02)00117-7
- Cremers, V.; Puurunen, R. L.; Dendooven, J. *Appl. Phys. Rev.* **2019**, *6*, 021302. doi:10.1063/1.5060967
- Johnson, R. W.; Hultqvist, A.; Bent, S. F. *Mater. Today* **2014**, *17*, 236–246. doi:10.1016/j.mattod.2014.04.026
- Lim, B. S.; Rahtu, A.; Gordon, R. G. *Nat. Mater.* **2003**, *2*, 749–754. doi:10.1038/nmat1000
- King, D. M.; Liang, X.; Weimer, A. W. *Powder Technol.* **2012**, *221*, 13–25. doi:10.1016/j.powtec.2011.12.020
- Loscutoff, P. W.; Zhou, H.; Clendenning, S. B.; Bent, S. F. *ACS Nano* **2010**, *4*, 331–341. doi:10.1021/nn901013r
- Adamczyk, N. M.; Dameron, A. A.; George, S. M. *Langmuir* **2008**, *24*, 2081–2089. doi:10.1021/la7025279
- Loscutoff, P. W.; Lee, H.-B.-R.; Bent, S. F. *Chem. Mater.* **2010**, *22*, 5563–5569. doi:10.1021/cm1016239
- Al Zoubi, W.; Kamil, M. P.; Fatimah, S.; Nashrah, N.; Ko, Y. G. *Prog. Mater. Sci.* **2020**, *112*, 100663. doi:10.1016/j.pmatsci.2020.100663
- Gomez-Romero, P. *Adv. Mater. (Weinheim, Ger.)* **2001**, *13*, 163–174. doi:10.1002/1521-4095(200102)13:3<163::aid-adma163>3.0.co;2-u
- Judeinstein, P.; Sanchez, C. *J. Mater. Chem.* **1996**, *6*, 511–525. doi:10.1039/jm9960600511
- Lee, B. H.; Anderson, V. R.; George, S. M. *Meet. Abstr.* **2011**, *MA2011-02*, 1846. doi:10.1149/ma2011-02/26/1846
- Lee, B. H.; Yoon, B.; Abdulagatov, A. I.; Hall, R. A.; George, S. M. *Adv. Funct. Mater.* **2013**, *23*, 532–546. doi:10.1002/adfm.201200370
- Dameron, A. A.; Seghete, D.; Burton, B. B.; Davidson, S. D.; Cavanagh, A. S.; Bertrand, J. A.; George, S. M. *Chem. Mater.* **2008**, *20*, 3315–3326. doi:10.1021/cm7032977
- Lidor-Shalev, O.; Leifer, N.; Ejgenberg, M.; Aviv, H.; Perelshtein, I.; Goobes, G.; Noked, M.; Rosy. *Batteries Supercaps* **2021**, *4*, 1739–1748. doi:10.1002/batt.202100152
- Park, Y.-S.; Kim, H.; Cho, B.; Lee, C.; Choi, S.-E.; Sung, M. M.; Lee, J. S. *ACS Appl. Mater. Interfaces* **2016**, *8*, 17489–17498. doi:10.1021/acsami.6b01856
- Yoon, B.; O'Patches, J. L.; Seghete, D.; Cavanagh, A. S.; George, S. M. *Chem. Vap. Deposition* **2009**, *15*, 112–121. doi:10.1002/cvde.200806756
- Peng, Q.; Gong, B.; VanGundy, R. M.; Parsons, G. N. *Chem. Mater.* **2009**, *21*, 820–830. doi:10.1021/cm8020403
- Lee, B. H.; Anderson, V. R.; George, S. M. *ACS Appl. Mater. Interfaces* **2014**, *6*, 16880–16887. doi:10.1021/am504341r
- Kint, J.; Mattelaer, F.; Vandenbroucke, S. S. T.; Muriqi, A.; Minjauw, M. M.; Nisula, M.; Vereecken, P. M.; Nolan, M.; Dendooven, J.; Detavernier, C. *Chem. Mater.* **2020**, *32*, 4451–4466. doi:10.1021/acs.chemmater.9b05116
- Van de Kerckhove, K.; Mattelaer, F.; Dendooven, J.; Detavernier, C. *Dalton Trans.* **2017**, *46*, 4542–4553. doi:10.1039/c7dt00374a
- Song, Z.; Fathizadeh, M.; Huang, Y.; Chu, K. H.; Yoon, Y.; Wang, L.; Xu, W. L.; Yu, M. *J. Membr. Sci.* **2016**, *510*, 72–78. doi:10.1016/j.memsci.2016.03.011
- Ishchuk, S.; Taffa, D. H.; Hazut, O.; Kaynan, N.; Yerushalmi, R. *ACS Nano* **2012**, *6*, 7263–7269. doi:10.1021/nn302370y
- Sarkar, D.; Ishchuk, S.; Taffa, D. H.; Kaynan, N.; Berke, B. A.; Bendikov, T.; Yerushalmi, R. *J. Phys. Chem. C* **2016**, *120*, 3853–3862. doi:10.1021/acs.jpcc.5b11795
- Brown, J. J.; Hall, R. A.; Kladitis, P. E.; George, S. M.; Bright, V. M. *ACS Nano* **2013**, *7*, 7812–7823. doi:10.1021/nn402733g
- Abdulagatov, A. I.; Hall, R. A.; Sutherland, J. L.; Lee, B. H.; Cavanagh, A. S.; George, S. M. *Chem. Mater.* **2012**, *24*, 2854–2863. doi:10.1021/cm300162v
- Abdulagatov, A. I.; Terauds, K. E.; Travis, J. J.; Cavanagh, A. S.; Raj, R.; George, S. M. *J. Phys. Chem. C* **2013**, *117*, 17442–17450. doi:10.1021/jp4051947
- Cao, Y.-Q.; Zhu, L.; Li, X.; Cao, Z.-Y.; Wu, D.; Li, A.-D. *Dalton Trans.* **2015**, *44*, 14782–14792. doi:10.1039/c5dt00384a
- Van de Kerckhove, K.; Mattelaer, F.; Deduytsche, D.; Vereecken, P. M.; Dendooven, J.; Detavernier, C. *Dalton Trans.* **2016**, *45*, 1176–1184. doi:10.1039/c5dt003840e
- Son, S.-B.; Wang, Y.; Xu, J.; Li, X.; Groner, M.; Stokes, A.; Yang, Y.; Cheng, Y.-T.; Ban, C. *ACS Appl. Mater. Interfaces* **2017**, *9*, 40143–40150. doi:10.1021/acsami.7b08960
- Xie, Q.; Jiang, Y.-L.; Detavernier, C.; Deduytsche, D.; Van Meirhaeghe, R. L.; Ru, G.-P.; Li, B.-Z.; Qu, X.-P. *J. Appl. Phys.* **2007**, *102*, 083521. doi:10.1063/1.2798384
- Elam, J. W.; Schuisky, M.; Ferguson, J. D.; George, S. M. *Thin Solid Films* **2003**, *436*, 145–156. doi:10.1016/s0040-6090(03)00533-9

37. Yoon, B.; Seghete, D.; Cavanagh, A. S.; George, S. M. *Chem. Mater.* **2009**, *21*, 5365–5374. doi:10.1021/cm9013267
38. Kim, B.; Lee, N.; Park, S.; Park, T.; Song, J.; Han, S.; Park, H.; Lee, D.; Kim, H.; Jeon, H. *J. Alloys Compd.* **2021**, *857*, 157931. doi:10.1016/j.jallcom.2020.157931
39. Muriqi, A.; Nolan, M. *Dalton Trans.* **2020**, *49*, 8710–8721. doi:10.1039/d0dt01376e
40. Muriqi, A.; Karppinen, M.; Nolan, M. *Dalton Trans.* **2021**, *50*, 17583–17593. doi:10.1039/d1dt03195c
41. Kaur, P.; Muriqi, A.; Wree, J.-L.; Ghiyasi, R.; Safdar, M.; Nolan, M.; Karppinen, M.; Devi, A. *Dalton Trans.* **2022**, *51*, 5603–5611. doi:10.1039/d2dt00353h
42. Tanskanen, A.; Sundberg, P.; Nolan, M.; Karppinen, M. *Thin Solid Films* **2021**, *736*, 138896. doi:10.1016/j.tsf.2021.138896
43. Sundberg, P.; Karppinen, M. *Eur. J. Inorg. Chem.* **2014**, 968–974. doi:10.1002/ejic.201301560
44. Sood, A.; Sundberg, P.; Malm, J.; Karppinen, M. *Appl. Surf. Sci.* **2011**, *257*, 6435–6439. doi:10.1016/j.apsusc.2011.02.022
45. Bach, U.; Lupo, D.; Comte, P.; Moser, J. E.; Weissörtel, F.; Salbeck, J.; Spreitzer, H.; Grätzel, M. *Nature* **1998**, *395*, 583–585. doi:10.1038/26936
46. Linsebigler, A. L.; Lu, G.; Yates, J. T., Jr. *Chem. Rev.* **1995**, *95*, 735–758. doi:10.1021/cr00035a013
47. Grätzel, M. *Nature* **2001**, *414*, 338–344. doi:10.1038/35104607
48. Huertas, Z. C.; Settipani, D.; Flox, C.; Morante, J. R.; Kallio, T.; Biendicho, J. J. *Sci. Rep.* **2022**, *12*, 137. doi:10.1038/s41598-021-04105-x
49. Kresse, G.; Furthmüller, J. *Phys. Rev. B: Condens. Matter Mater. Phys.* **1996**, *54*, 11169–11186. doi:10.1103/physrevb.54.11169
50. Liu, J.; Saedy, S.; Verma, R.; van Ommen, J. R.; Nolan, M. *ChemRxiv* **2020**, 1–44. doi:10.26434/chemrxiv.12320855
51. Jenness, G. R.; Seiter, J.; Shukla, M. K. *Phys. Chem. Chem. Phys.* **2018**, *20*, 18850–18861. doi:10.1039/c8cp02590h
52. Blöchl, P. E. *Phys. Rev. B* **1994**, *50*, 17953–17979. doi:10.1103/physrevb.50.17953
53. Perdew, J. P.; Burke, K.; Ernzerhof, M. *Phys. Rev. Lett.* **1996**, *77*, 3865–3868. doi:10.1103/physrevlett.77.3865
54. Grimme, S.; Antony, J.; Ehrlich, S.; Krieg, H. *J. Chem. Phys.* **2010**, *132*, 154104. doi:10.1063/1.3382344
55. Ali, S.; Juntunen, T.; Sintonen, S.; Ylivaara, O. M. E.; Puurunen, R. L.; Lipsanen, H.; Tittonen, I.; Hannula, S.-P. *Nanotechnology* **2016**, *27*, 445704. doi:10.1088/0957-4484/27/44/445704

License and Terms

This is an open access article licensed under the terms of the Beilstein-Institut Open Access License Agreement (<https://www.beilstein-journals.org/bjnano/terms>), which is identical to the Creative Commons Attribution 4.0 International License (<https://creativecommons.org/licenses/by/4.0>). The reuse of material under this license requires that the author(s), source and license are credited. Third-party material in this article could be subject to other licenses (typically indicated in the credit line), and in this case, users are required to obtain permission from the license holder to reuse the material.

The definitive version of this article is the electronic one which can be found at:
<https://doi.org/10.3762/bjnano.13.103>